

Please amend the paragraph on page 5, line 23, as follows:

02 (Amended) Figure 3 is an explanatory diagram showing a method for manufacturing a gallium nitride compound semiconductor according to a third embodiment of the present invention.

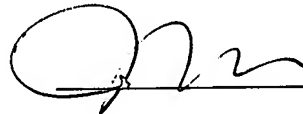
REMARKS

The specification have been amended to remove errors in the "Brief Description of the Drawings" section. The changes were made to match the brief description of the drawings to the filed figures and the discussion in the detailed description and background sections. No amendments have been made for reasons relating to patentability, and no new matter has been introduced by way of this amendment. Full examination and favorable action are requested.

Please apply any charges not covered, or any credits, to Deposit Account 50-0591 (Reference No. 08228.020001).

Respectfully submitted,

Date: 5/2/00



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